

GREEN LIGHT EMITTING DIODE

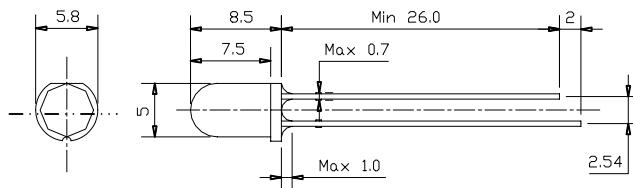
LPG-510CWH

1. Features

1-1. The radiation substrate material is

InGaN/SiC

1-2. Available for pulse operating



2. Applications

2-1. Electronic signs and signals

2-2. Small area illumination

*NOTE 1. All dimensions in "mm"

2-3. Back-light

2-4. Indicator

3. Absolute Maximum Ratings (Ta=25°C)

Item	Symbol	Rating	Unit
Reverse Voltage	V _R	5	V
Forward Current	I _F	30	mA
Pulse Forward Current* ¹	I _{FP}	100	mA
Power Dissipation	P _D	125	mW
LED Junction Temperature	T _j	125	°C
Operating Temperature	T _{opr}	-25~+80	°C
Storage Temperature	T _{stg}	-30~+100	°C

*¹ tw=100μsec, T=10msec

4. Electro-Optical Characteristics (Ta=25°C)

Item	Symbol	Condition	Min	Typ	Max	Unit
Forward Voltage	V _F	I _F =20mA		3.5	4.0	V
Reverse Current	I _R	V _R =5V			10	μA
Luminous Intensity	I _V	I _F =20mA		4000		mcd
Peak Wavelength	λ _p	I _F =20mA		525		nm
Capacitance	C _t	f=1MHz		40		pF
Angle				30		deg.

5. Notes

LBG-□□□□□ LEDs are class 2 ESD sensitive.

Please observe appropriate precautions handling and processing.